4V Drive Nch MOS FET RSS095N05

Structure

Silicon N-channel MOS FET

Features

- 1) Built-in G-S Protection Diode.
- 2) Small Surface Mount Package (SOP8).

Applications

Power switching , DC / DC converter , Inverter

Packaging dimensions

| Package | Taping |
|-----------------------------|--------|
| Code | TB |
| Basic ordering unit(pieces) | 2500 |

● Absolute maximum ratings (Ta=25°C)

| Parameter | Symbol | | Limits | Unit | |
|-------------------------|------------|----------------|-------------|------|---|
| Drain-source voltage | V_{DSS} | | 45 | V | |
| Gate-source voltage | V_{GSS} | | 20 | V | |
| Drain current | Continuous | I_D | | ±9.5 | Α |
| Diain current | Pulsed | I_{DP} | *1 | ±38 | Α |
| Source current | Continuous | I _S | | 1.6 | Α |
| (Body diode) | Pulsed | I_{SP} | *1 | 38 | Α |
| Total power dissipation | P_{D} | *2 | 2 | W | |
| Chanel temperature | T_{ch} | | 150 | °C | |
| Range of Storage temp | T_{stg} | | -55 to +150 | °C | |

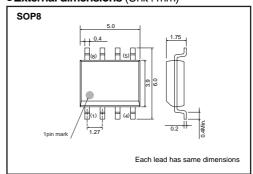
^{*1} PW≤10μs, Duty cycle≤1%

●Thermal resistance

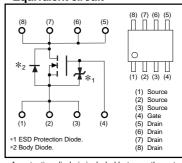
| Parameter | Symbol | Limits | Unit |
|-------------------|-------------------------|--------|------|
| Chanel to ambient | R _{th(ch-a)} * | 62.5 | °C/W |

^{*} Mounted on a ceramic board

●External dimensions (Unit : mm)



●Equivalent circuit



^{*} A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use.Use a protection circuit when the fixed voltage are exceeded.

^{*2} Mounted on a ceramic board

●Electrical characteristics (Ta=25°C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-----------------------------------------|------------------------|------|------|------|------|-----------------------------------------------|
| Gate-source leakage | I _{GSS} | _ | - | 10 | μΑ | V _{GS} =20V, V _{DS} =0V |
| Drain-source breakdown voltage | V _(BR) DSS | 45 | _ | _ | ٧ | I _D = 1mA, V _{GS} =0V |
| Zero gate voltage drain current | IDSS | _ | _ | 1 | μΑ | V _{DS} = 45V, V _{GS} =0V |
| Gate threshold voltage | V _{GS (th)} | 1.0 | _ | 2.5 | ٧ | V _{DS} = 10V, I _D = 1mA |
| Static drain-source on-state resistance | R _{DS (on)} * | _ | 11 | 16 | mΩ | I _D = 9.5A, V _{GS} = 10V |
| | | _ | 14 | 20 | mΩ | I _D = 9.5A, V _{GS} = 4.5V |
| | | _ | 15 | 21 | mΩ | I _D = 9.5A, V _{GS} = 4V |
| Forward transfer admittance | Y _{fs} * | 10.0 | - | _ | S | V _{DS} = 10V, I _D = 9.5A |
| Input capacitance | Ciss | _ | 1830 | _ | pF | V _{DS} = 10V |
| Output capacitance | Coss | _ | 410 | _ | pF | V _{GS} =0V |
| Reverse transfer capacitance | Crss | _ | 210 | _ | pF | f=1MHz |
| Turn-on delay time | t _{d (on)} * | _ | 20 | _ | ns | V _{DD} ≒ 25V |
| Rise time | tr * | _ | 35 | _ | ns | ID= 5.0A |
| Turn-off delay time | td (off) * | _ | 78 | _ | ns | V _{GS} = 10V R _L =5Ω |
| Fall time | t _f * | _ | 31 | _ | ns | R _G =10Ω |
| Total gate charge | Qg * | _ | 18.9 | 26.5 | nC | V _{DD} =25V V _{GS} =5V |
| Gate-source charge | Q _{gs} * | _ | 4.9 | _ | nC | I _D = 9.5A |
| Gate-drain charge | Q _{gd} * | _ | 7.2 | _ | nC | R _L =2.6Ω R _G =10Ω |

^{*}Pulsed

Body diode characteristics (Source-Drain) (Ta=25 $^{\circ}$ C)

| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions |
|-----------------|--------|------|------|------|------|--------------------------------------------|
| Forward voltage | Vsp* | _ | _ | 1.2 | V | I _S = 9.5A, V _{GS} =0V |

^{*}Pulsed

•Electrical characteristic curves

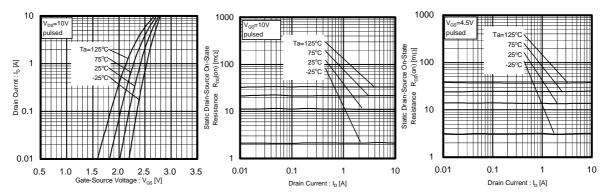
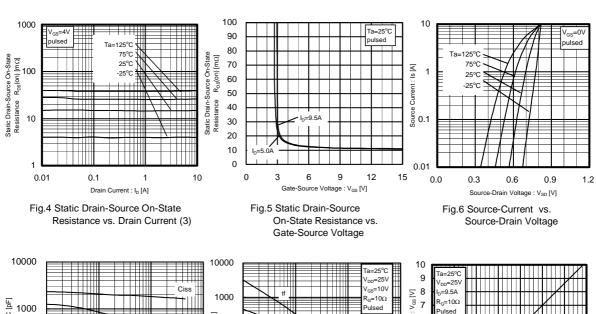


Fig.1 Typical Transfer Characteristics

Fig.2 Static Drain-Source On-State Resistance vs. Drain Current (1)

Fig.3 Static Drain-Source On-State Resistance vs. Drain Current (2)



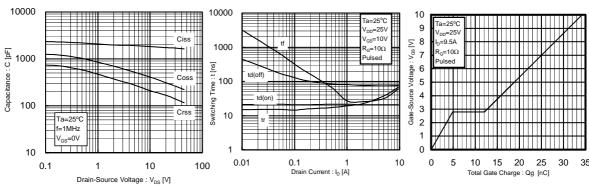


Fig.7 Typical capacitance vs. Source-Drain Voltage

Fig.8 Switching Characteristics

Fig.9 Dynamic Input Characteristics

Measurement circuits

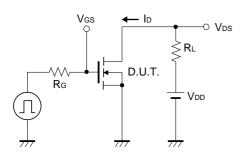


Fig.10 Switching Time Test Circuit

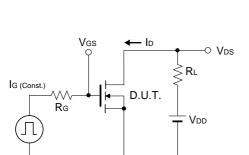


Fig.12 Gate Charge Test Circuit

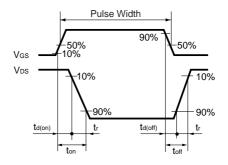


Fig.11 Switching Time Waveforms

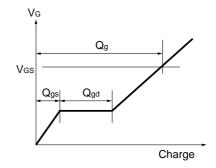


Fig.13 Gate Charge Waveform

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